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ZFTEX

## ZXLD1362

60V 1A LED DRIVER WITH AEC-Q100

## Description

## Pin Assignments

The ZXLD1362 is a continuous mode inductive step-down converter with integrated switch and high side current sense.

It operates from an input supply from 6 V to 60 V driving single or multiple series connected LEDs efficiently externally adjustable output current up to 1A.
The ZXLD1362 has been qualified to AEC-Q100 Grade 1 enabling operation in ambient temperatures from $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$.
The output current can be adjusted by applying a DC voltage or a PWM waveform. 100.1 adjustment of output current is possible using PWM control.
Applying 0.2 V or lower to the ADJ pin turns the output off and switches the device into a low current standby state.

## Features

- Simple low parts count
- Single pin on/off and brightness control using DC voltage or PWM
- High efficiency (up to 95\%)
- Wide input voltage range: 6 V to 60 V
- Up to 1 MHz switching frequency
- Qualified to AEC-Q100 Grade 1
- Automotive Grade version available (ZXLD1362Q)
- Typical 2\% output current accuracy
- Thermally enhanced TSOT25: $\theta_{\mathrm{JA}} 82^{\circ} \mathrm{C} / \mathrm{W}$
- Available in Green Molding
- Totally Lead-Free \& Fully RoHS Compliant (Notes 1 \& 2)
- Halogen and Antimony Free. "Green" Device (Note 3)


Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) \& 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain $<900 \mathrm{ppm}$ bromine, $<900 \mathrm{ppm}$ chlorine ( $<1500 \mathrm{ppm}$ total $\mathrm{Br}+\mathrm{Cl}$ ) and <1000ppm antimony compounds.

## Typical Application Circuit



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## Pin Description

| Name | Pin No. | Function |
| :---: | :---: | :---: |
| LX | 1 | Drain of NDMOS switch |
| GND | 2 | Ground (0V) |
| ADJ | 3 | Multi-function On/Off and brightness control pin: <br> Leave floating for normal operation. $\left(\mathrm{V}_{\mathrm{ADJ}}=\mathrm{V}_{\mathrm{REF}}=1.25 \mathrm{~V}\right.$ giving nominal average output current $\text { loutnom }=0.1 / R S)$ <br> Drive to voltage below 0.2 V to turn off output current <br> Drive with DC voltage ( $0.3 \mathrm{~V}<\mathrm{V}_{\mathrm{ADJ}}<2.5 \mathrm{~V}$ ) to adjust output current from $25 \%$ to $200 \%$ of $\mathrm{I}_{\text {OUTnom }}$ Connect a capacitor from this pin to ground to increase soft-start time. <br> Soft-start time increases approximately $200 \mu \mathrm{~s} / \mathrm{nF}$. |
| $I_{\text {SENSE }}$ | 4 | Connect resistor $R_{S}$ from this pin to $V_{\mathbb{I N}}$ to define nominal average output current loutnom $=0.1 / R_{S}$ (Note: $\mathrm{R}_{\text {SMIN }}=0.1 \Omega$ with ADJ pin open circuit) |
| $\mathrm{V}_{\text {IN }}$ | 5 | Input voltage (6V to 60V). Decouple to ground with $4.7 \mu \mathrm{~F}$ of higher X 7 R ceramic capacitor close to device. |

## Block Diagram



Figure 1 Block Diagram

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## ZXLD1362

Absolute Maximum Ratings (Note 4) ( $\mathrm{C}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Symbol | Parameter | Rating | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\text {IN }}$ | Input Voltage | -0.3 to +65 | V |
| $\mathrm{~V}_{\text {SENSE }}$ | ISENSE Voltage (Note 5) | +0.3 to -5 | V |
| $\mathrm{~V}_{\text {LX }}$ | LX Output Voltage | -0.3 to +65 | V |
| $\mathrm{~V}_{\text {ADJ }}$ | Adjust Pin Input Voltage | -0.3 to +6 | V |
| $\mathrm{I}_{\text {LX }}$ | Switch Output Current | 1.25 | A |
| $\mathrm{P}_{\text {TOT }}$ | Power Dissipation <br> (Refer to Package thermal de-rating curve on page 16) | 1 | W |
| $\mathrm{~T}_{\text {ST }}$ | Storage Temperature | -55 to +150 | 150 |
| $\mathrm{~T}_{\text {J MAX }}$ | Junction Temperature | ${ }^{\circ} \mathrm{C}$ |  |

Note: $\quad 4$ All voltages unless otherwise stated are measured with respect to GND.
5. $V_{\text {SENSE }}$ is measured with respect to $V_{I N}$.

Caution: Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at conditions between maximum recommended operating conditions and absolute maximum ratings is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

| ESD Susceptibility | Rating | Unit |
| :--- | :---: | :---: |
|  | 500 | V |
| Human Body Model | 75 | V |
| Machine Model |  |  |

Caution: Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices.
The human body model is a 100 pF capacitor discharge through a $1.5 \mathrm{k} \Omega$ resistor pin. The machine model is a 200 pF capacitor discharged directly into each pin.

## Thermal Resistance

| Symbol | Parameter | Rating | Unit |
| :---: | :---: | :---: | :---: |
| $\Theta_{\mathrm{JA}}$ | Junction to Ambient | 82 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\Psi_{\mathrm{JB}}$ | Junction to Board | 33 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## Recommended Operating Conditions $\left(\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\right.$, unless otherwise specified.)

| Symbol | Parameter | Min | Max | Units |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN }}$ | Input Voltage Range (Note 6) | 6 | 60 | V |
| $\mathrm{I}_{\text {LX }}$ | Maximum recommended continuous/RMS switch current |  | 1 | A |
| $\mathrm{~V}_{\text {ADJ }}$ | External control voltage range on ADJ pin for DC brightness control (Note 7) | 0.3 | 2.5 | V |
| $\mathrm{~V}_{\text {ADJoff }}$ | DC voltage on ADJ pin to ensure devices is off |  | 0.25 | V |
| $\mathrm{t}_{\text {ONMIN }}$ | Minimum switch on-time |  | 800 | ns |
| $\mathrm{f}_{\mathrm{LX} \text { max }}$ | Recommended maximum operating frequency (Note 8) |  | 625 | kHz |
| $\mathrm{D}_{\text {LX }}$ | Duty cycle range | 0.01 | 0.99 |  |
| $\mathrm{~T}_{\text {A }}$ | Ambient operating temperature range | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |

Notes: $\quad 6 . V_{I N}>16 \mathrm{~V}$ to fully enhance output transistor. Otherwise out current must be derated - see graphs. Operation at low supply may cause excessive heating due to increased on-resistance. Tested at 7 V guaranteed for 6 V by design.
7. $100 \%$ brightness corresponds to $\mathrm{V}_{\mathrm{ADJ}}=\mathrm{V}_{\mathrm{ADJ}(\mathrm{nom})}=\mathrm{V}_{\text {REF }}$. Driving the ADJ pin above $\mathrm{V}_{\text {REF }}$ will increase the $\mathrm{V}_{\text {SENSE }}$ threshold and output current proportionally.
8. ZXLD1362 will operate at higher frequencies but accuracy will be affected due to propagation delays.

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Electrical Characteristics (@ $\mathrm{V}_{\mathbb{I N}}=24 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Symbol | Parameter | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {SU }}$ | Internal regulator start-up threshold |  |  | 4.85 |  | V |
| $V_{\text {SD }}$ | Internal regulator shutdown threshold |  |  | 4.75 |  | V |
| IINQoff | Quiescent supply current with output off | ADJ pin grounded |  | 65 | 90 | $\mu \mathrm{A}$ |
| İNQon | Quiescent supply current with output switching (Note 9) | ADJ pin floating, $\mathrm{L}=68 \mu \mathrm{H}$, <br> 3 LEDs, $\mathrm{f}=260 \mathrm{kHz}$ |  | 1.8 |  | mA |
| V SEnse | Mean current sense threshold voltage (Defines LED current setting accuracy) | Measured on ISENSE pin with respect to $\mathrm{V}_{\mathrm{IN}} \mathrm{V}_{\text {ADJ }}=1.25 \mathrm{~V}$ | 95 | 100 | 105 | mV |
| $\mathrm{V}_{\text {SENSEHYS }}$ | Sense threshold hysteresis |  |  | $\pm 10$ |  | \% |
| Isense | ISENSE pin input current | $\mathrm{V}_{\text {SENSE }}=\mathrm{V}_{\text {IN }}-0.1$ |  | 4 | 10 | $\mu \mathrm{A}$ |
| $V_{\text {Ref }}$ | Internal reference voltage | Measured on ADJ pin with pin floating |  | 1.25 |  | V |
| $\Delta \mathrm{V}_{\text {REF } / \Delta T}$ | Temperature coefficient of $\mathrm{V}_{\text {REF }}$ |  |  | 50 |  | ppm/ ${ }^{\circ} \mathrm{C}$ |
| $V_{\text {ADJ }}$ | External control voltage range on ADJ pin for DC brightness control (Note 7) |  | 0.3 |  | 2.5 | V |
| $V_{\text {ADJoff }}$ | DC voltage on ADJ pin to switch device from active (on) state to quiescent (off) state | $\mathrm{V}_{\text {ADJ }}$ falling | 0.15 | 0.2 | 0.27 | V |
| $\mathrm{V}_{\text {ADJon }}$ | DC voltage on ADJ pin to switch device from quiescent (off) state to active (on) state | $\mathrm{V}_{\text {ADJ }}$ rising | 0.2 | 0.25 | 0.3 | V |
| $\mathrm{R}_{\text {ADJ }}$ | Resistance between ADJ pin and $\mathrm{V}_{\text {REF }}$ | $\begin{aligned} & 0<\mathrm{V}_{\mathrm{ADJ}}<\mathrm{V}_{\mathrm{REF}} \\ & \mathrm{~V}_{\mathrm{ADJ}}>\mathrm{V}_{\mathrm{REF}}+100 \mathrm{mV} \end{aligned}$ | $\begin{gathered} \hline 30 \\ 10.4 \end{gathered}$ | $\begin{gathered} \hline 50 \\ 14.2 \end{gathered}$ | $\begin{aligned} & \hline 65 \\ & 18 \end{aligned}$ | k $\Omega$ |
| ILXmean | Continuous LX switch current |  |  |  | 1 | A |
| RLX | LX switch 'On' resistance | @ ILX $=1 \mathrm{~A}$ |  | 0.5 | 1.0 | $\Omega$ |
| ILX(leak) | LX switch leakage current |  |  |  | 5 | $\mu \mathrm{A}$ |
| DPWM(LF) | Duty cycle range of PWM signal applied to ADJ pin during low frequency PWM dimming mode | PWM frequency $<300 \mathrm{~Hz}$ PWM amplitude $=\mathrm{V}_{\text {REF }}$ | 0.001 |  | 1 |  |
|  | Brightness control range | Measured on ADJ pin |  | 1000:1 |  |  |
| $\mathrm{DC}_{\text {ADJ }}$ | DC Brightness control range | Note 10 |  | 5:1 |  |  |
| tss | Soft start time | Time taken for output current to reach $90 \%$ of final value after voltage on ADJ pin has risen above 0.3 V . Requires external capacitor $22 n F$. See graphs for more details |  | 2 |  | ms |
| fLX | Operating frequency <br> (See graphs for more details) | ADJ pin floating $\mathrm{L}=68 \mu \mathrm{H}(0.1 \mathrm{~V})$ lout $=1 \mathrm{~A} @ \mathrm{~V}_{\text {LED }}=3.6 \mathrm{~V}$ Driving 3 LEDs |  | 300 |  | kHz |
| tonmin | Minimum switch 'ON' time | LX switch 'ON' |  | 130 |  | ns |
| toffmin | Minimum switch 'OFF' time | LX switch 'OFF' |  | 70 |  | ns |

Notes: $\quad 9$. Static current of device is approximately $700 \mu \mathrm{~A}$, see Graph, Page 16.
10. Ratio of maximum brightness to minimum brightness before shutdown $V_{R E F}=1.25 / 0.3$. $V_{R E F}$ externally driven to 2.5 V , ratio 10:1.

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## Device Description

The device, in conjunction with the coil (L1) and current sense resistor ( $\mathrm{R}_{\mathrm{s}}$ ), forms a self-oscillating continuous-mode buck converter.
Device operation (refer to Figure 1 - Block diagram and Figure 2 Operating waveforms)


Figure 2 Theoretical Operating Waveforms

Operation can be best understood by assuming that the ADJ pin of the device is unconnected and the voltage on this pin ( $\mathrm{V}_{\mathrm{ADJ}}$ ) appears directly at the (+) input of the comparator.

When input voltage $\mathrm{V}_{\mathrm{IN}}$ is first applied, the initial current in L 1 and $\mathrm{R}_{\mathrm{S}}$ is zero and there is no output from the current sense circuit. Under this condition, the (-) input to the comparator is at ground and its output is high. This turns MN on and switches the LX pin low, causing current to flow from $\mathrm{V}_{\mathrm{IN}}$ to ground, via $\mathrm{R}_{\mathrm{S}}, \mathrm{L} 1$ and the $\mathrm{LED}(\mathrm{s})$. The current rises at a rate determined by $\mathrm{V}_{\mathrm{IN}}$ and L 1 to produce a voltage ramp ( $\mathrm{V}^{\mathrm{SENSE}}$ ) across $\mathrm{R}_{\mathrm{S}}$. The supply referred voltage $\mathrm{V}_{\text {SENSE }}$ is forced across internal resistor R1 by the current sense circuit and produces a proportional current in internal resistors R2 and R3. This produces a ground referred rising voltage at the (-) input of the comparator. When this reaches the threshold voltage ( $\mathrm{V}_{\mathrm{ADJ}}$ ), the comparator output switches low and MN turns off. The comparator output also drives another NMOS switch, which bypasses internal resistor R3 to provide a controlled amount of hysteresis. The hysteresis is set by R3 to be nominally $10 \%$ of $V_{\text {ADJ }}$.

When MN is off, the current in L1 continues to flow via D 1 and the LED(s) back to $\mathrm{V}_{\mathrm{IN}}$. The current decays at a rate determined by the LED(s) and diode forward voltages to produce a falling voltage at the input of the comparator. When this voltage returns to $\mathrm{V}_{\mathrm{ADJ}}$, the comparator output switches high again. This cycle of events repeats, with the comparator input ramping between limits of $\mathrm{V}_{\mathrm{ADJ}} \pm 10 \%$.

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## Device Description (cont.)

## Switching Thresholds

With $V_{A D J}=V_{R E F}$, the ratios of $R 1, R 2$ and $R 3$ define an average $V_{\text {SENSE }}$ switching threshold of 100 mV (measured on the $I_{\text {SENSE }}$ pin with respect to $\mathrm{V}_{\mathrm{IN}}$ ). The average output current loutnom is then defined by this voltage and $\mathrm{R}_{\mathrm{S}}$ according to:

$$
\text { louTnom }=100 \mathrm{mV} / \mathrm{Rs}_{\mathrm{s}}
$$

Nominal ripple current is $\pm 10 \mathrm{mV} / \mathrm{R}_{\mathrm{S}}$

## Adjusting output current

The device contains a low pass filter between the ADJ pin and the threshold comparator and an internal current limiting resistor (50k $\Omega$ nom) between ADJ and the internal reference voltage. This allows the ADJ pin to be overdriven with either

DC or pulse signals to change the $\mathrm{V}_{\text {SENSE }}$ switching threshold and adjust the output current.
Details of the different modes of adjusting output current are given in the applications section.

## Output Shutdown

The output of the low pass filter drives the shutdown circuit. When the input voltage to this circuit falls below the threshold ( 0.2 V nom.), the internal regulator and the output switch are turned off. The voltage reference remains powered during shutdown to provide the bias current for the shutdown circuit. Quiescent supply current during shutdown is nominally $60 \mu \mathrm{~A}$ and switch leakage is below $5 \mu \mathrm{~A}$.

## Actual Operating Waveforms


$\mathrm{V}_{\mathrm{IN}}=60 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=0.1 \mathrm{~V}, \mathrm{~L}=100 \mu \mathrm{H}$ Normal Operation.
Output Current (Ch1) and LX Voltage (Ch2) Tek Stop: $10.0 \mathrm{MS} / \mathrm{s} \quad 353 \mathrm{Acqs}$


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## Typical Characteristics





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## Typical Characteristics (cont.)




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## Typical Characteristics (cont.)




ZXLD1362 Efficiency
$L=100 \mu \mathrm{H}$


## Typical Characteristics (cont.)



ZXLD1362 Switching Frequency
$L=100 \mu \mathrm{H}$


$$
-1 \text { LED }-3 \text { LED }-5 \text { LED }-7 \text { LED }-9 \text { LED }-11 \text { LED } 13 \text { LED }-15 \text { LED }
$$



## Typical Characteristics (cont.)




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## Typical Characteristics (cont.)

ZXLD1362 Output Current
$L=220 \mu \mathrm{H}$

-1 LED -3 LED $* 5$ LED -7 LED -9 LED -11 LED -13 LED -15 LED
ZXLD1362 Output Current


ZXLD1362 Efficiency
$\mathrm{L}=220 \mu \mathrm{H}$


## Typical Characteristics (cont.)


$L=2200 \mu \mathrm{H}$


$$
-1 \text { LED }-3 \text { LED } \sim 5 \text { LED }-7 \text { LED }-9 \text { LED }-11 \text { LED }-13 \text { LED }-15 \text { LED }
$$

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## Typical Characteristics (cont.)



Supply voltage (V)

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## Typical Characteristics (cont.)





## Application Information

## Setting Nominal Average Output Current with External Resistor Rs

The nominal average output current in the LED(s) is determined by the value of the external current sense resistor ( $\mathrm{R}_{\mathrm{S}}$ ) connected between $\mathrm{V}_{\mathbb{I N}}$ and $I_{\text {SENSE }}$ and is given by:
$I_{\text {OUTnom }}=0.1 / R_{S}\left[\right.$ for $\left.R_{S}>0.1 \Omega\right]$

The table below gives values of nominal average output current for several preferred values of current setting resistor ( $\mathrm{R}_{\mathrm{S}}$ ) in the typical application circuit shown on page 1 :

| $\mathbf{R}_{\mathbf{S}}(\Omega)$ | Nominal Average <br> Output Current <br> $(\mathrm{mA})$ |
| :---: | :---: |
| 0.1 | 1000 |
| 0.13 | 760 |
| 0.15 | 667 |

The above values assume that the ADJ pin is floating and at a nominal voltage of $V_{R E F}(=1.25 \mathrm{~V})$. Note that $R_{S}=0.1 \Omega$ is the minimum allowed value of sense resistor under these conditions to maintain switch current below the specified maximum value.
It is possible to use different values of $R_{S}$ if the ADJ pin is driven from an external voltage. (See next section).

## Output Current Adjustment by External DC Control Voltage

The ADJ pin can be driven by an external dc voltage ( $\mathrm{V}_{\mathrm{ADJ}}$ ), as shown, to adjust the output current to a value above or below the nominal average value defined by $\mathrm{R}_{\mathrm{S}}$.


The nominal average output current in this case is given by:

$$
\mathrm{l}_{\text {Outdc }}=\left(\mathrm{V}_{\mathrm{ADJ}} / 1.25\right) \times\left(100 \mathrm{mV} / \mathrm{R}_{\mathrm{S}}\right)\left[\text { for } 0.3<\mathrm{V}_{\mathrm{ADJ}}<2.5 \mathrm{~V}\right]
$$

Note that $100 \%$ brightness setting corresponds to $\mathrm{V}_{\mathrm{ADJ}}=\mathrm{V}_{\mathrm{REF}}$. When driving the ADJ pin above $1.25 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}$ must be increased in proportion to prevent $l_{\text {Outdc }}$ exceeding 1A maximum.

The input impedance of the ADJ pin is $50 \mathrm{k} \Omega \pm 25 \%$ for voltages below $\mathrm{V}_{\mathrm{REF}}$ and $\mathbf{1 4 . 2 \mathrm { k } \Omega} \mathbf{\pm 2 5 \%}$ for voltages above $\mathrm{V}_{\mathrm{REF}}+100 \mathrm{mV}$.

## Output Current Adjustment by PWM Control

## Directly driving ADJ input

A Pulse Width Modulated (PWM) signal with duty cycle $\mathrm{D}_{\mathrm{PWM}}$ can be applied to the ADJ pin, as shown below, to adjust the output current to a value above or below the nominal average value set by resistor $\mathrm{R}_{\mathrm{S}}$ :


## Application Information (cont.)

## Driving the ADJ Input via Open Collector Transistor

The recommended method of driving the ADJ pin and controlling the amplitude of the PWM waveform is to use a small NPN switching transistor as shown below:


This scheme uses the 50 k resistor between the ADJ pin and the internal voltage reference as a pull-up resistor for the external transistor.

## Driving the ADJ Input from a Microcontroller

Another possibility is to drive the device from the open drain output of a microcontroller. The diagram below shows one method of doing this:


If the NMOS transistor within the microcontroller has high Gate / Drain capacitance, this arrangement can inject a negative spike into ADJ input of the 1362 and cause erratic operation but the addition of a Schottky clamp diode (cathode to ADJ) to ground and inclusion of a series resistor (3.3k) will prevent this. See the section on PWM dimming for more details of the various modes of control using high frequency and low frequency PWM signals.

## Shutdown Mode

Taking the ADJ pin to a voltage below 0.2 V for more than approximately $100 \mu$ s will turn off the output and supply current to a low standby level of $20 \mu \mathrm{~A}$ nominal.
Note that the ADJ pin is not a logic input. Taking the ADJ pin to a voltage above $\mathrm{V}_{\text {REF }}$ will increase output current above the $100 \%$ nominal average value. (See page 18 graphs for details).

## Soft-Start

An external capacitor from the ADJ pin to ground will provide a soft-start delay, by increasing the time taken for the voltage on this pin to rise to the turn-on threshold and by slowing down the rate of rise of the control voltage at the input of the comparator. Adding capacitance increases this delay by approximately $200 \mu \mathrm{~s} / \mathrm{nF}$. The graph below shows the variation of soft-start time for different values of capacitor.


## Application Information (cont.)

## $\mathrm{V}_{\mathrm{IN}}$ Capacitor Selection

A low ESR capacitor should be used for input decoupling, as the ESR of this capacitor appears in series with the supply source impedance and lowers overall efficiency. This capacitor has to supply the relatively high peak current to the coil and smooth the current ripple on the input supply.

To avoid transients into the IC, the size of the input capacitor will depend on the $\mathrm{V}_{\mathbb{I N}}$ voltage:

$$
\begin{aligned}
& \mathrm{V}_{\mathrm{IN}}=6 \text { to } 40 \mathrm{~V} \mathrm{C}_{\mathrm{IN}}=2.2 \mu \mathrm{~F} \\
& \mathrm{~V}_{\mathrm{IN}}=40 \text { to } 50 \mathrm{~V}_{\mathrm{IN}}=4.7 \mu \mathrm{~F} \\
& \mathrm{~V}_{\mathbb{I N}}=50 \text { to } 60 \mathrm{~V}_{\mathrm{IN}}=10 \mu \mathrm{~F}
\end{aligned}
$$

When the input voltage is approaches the output voltage the input current will increase putting more demand on the input capacitor. The minimum value of $2.2 \mu \mathrm{~F}$ may need to be increased to $4.7 \mu \mathrm{~F}$; higher values will improve performance at lower input voltages, especially when the source impedance is high. The input capacitor should be placed as close as possible to the IC.

For maximum stability over temperature and voltage, capacitors with $\mathrm{X} 7 \mathrm{R}, \mathrm{X} 5 \mathrm{R}$, or better dielectric is recommended. Capacitors with Y 5 V dielectric are not suitable for decoupling in this application and should NOT be used.

If higher voltages are used and the $\mathrm{C}_{\mathbb{I}}$ is $10 \mu \mathrm{~F}$. This can be an electrolytic capacitor provided a suitable $1 \mu \mathrm{~F}$ ceramic capacitor is also used and positioned as close the $\mathrm{V}_{\mathrm{IN}}$ of the IC as possible.

A suitable capacitor would be NACEW100M1006.3x8TR13F.
The following web sites are useful when finding alternatives:

## www.murata.com

www.niccomp.com
www.kemet.com

## Inductor Selection

Recommended inductor values for the ZXLD1362 are in the range $68 \mu \mathrm{H}$ to $220 \mu \mathrm{H}$.
Higher values of inductance are recommended at higher supply voltages in order to minimize errors due to switching delays, which result in increased ripple and lower efficiency. Higher values of inductance also result in a smaller change in output current over the supply voltage range. (see graphs pages 10-17). The inductor should be mounted as close to the device as possible with low resistance connections to the LX and $V_{\text {IN }}$ pins.

The chosen coil should have a saturation current higher than the peak output current and a continuous current rating above the required mean output current.

Suitable coils for use with the ZXLD1362 may be selected from the MSS range manufactured by Coilcraft, or the NPIS range manufactured by NIC components. The following websites may be useful in finding suitable components.

```
www.coilcraft.com
www.niccomp.com
www.wuerth-elektronik.de
```

The inductor value should be chosen to maintain operating duty cycle and switch 'on'/'off' times within the specified limits over the supply voltage and load current range.

## Application Information (cont.)

The graph Figure 3 below can be used to select a recommended inductor based on maintaining the ZXLD 1362 case temperature below $60^{\circ} \mathrm{C}$. For detailed performance characteristics for the inductor values $68,100,150$ and $220 \mu \mathrm{H}$ see graphs on pages 10-17.

## ZXLD1362 Minimum Recommended Inductor <br> Aluminium board, $2 \%$ Accuracy, $60^{\circ} \mathrm{C}$ Case Temperature



Figure 3 ZXLD1362 Minimum Recommended Inductor

## Diode Selection

For maximum efficiency and performance, the rectifier (D1) should be a fast low capacitance Schottky diode* with low reverse leakage at the maximum operating voltage and temperature.

They also provide better efficiency than silicon diodes, due to a combination of lower forward voltage and reduced recovery time.
It is important to select parts with a peak current rating above the peak coil current and a continuous current rating higher than the maximum output load current. It is very important to consider the reverse leakage of the diode when operating above $+85^{\circ} \mathrm{C}$. Excess leakage will increase the power dissipation in the device and if close to the load may create a thermal runaway condition.

The higher forward voltage and overshoot due to reverse recovery time in silicon diodes will increase the peak voltage on the LX output. If a silicon diode is used, care should be taken to ensure that the total voltage appearing on the LX pin including supply ripple, does not exceed the specified maximum value.
*A suitable Schottky diode would be PDS3100.

## Application Information (cont.)

## Reducing Output Ripple

Peak to peak ripple current in the LED(s) can be reduced, if required, by shunting a capacitor Cled across the LED(s) as shown below:


A value of $1 \mu \mathrm{~F}$ will reduce the supply ripple current by a factor three (approx.). Proportionally lower ripple can be achieved with higher capacitor values. Note that the capacitor will not affect operating frequency or efficiency, but it will increase start-up delay, by reducing the rate of rise of LED voltage.

By adding this capacitor the current waveform through the LED(s) changes from a triangular ramp to a more sinusoidal version without altering the mean current value.

## Operation at Low Supply Voltage

Below the under-voltage lockout threshold (VSD) the drive to the output transistor is turned off to prevent device operation with excessive onresistance of the output transistor. The output transistor is not full enhanced until the supply voltage exceeds approximately 17V. At supply voltages between $\mathrm{V}_{\text {SD }}$ and 17 V care must be taken to avoid excessive power dissipation due to the on-resistance.

If the supply voltage is always less than 30 V continuous an alternative device is available, the ZXLD1360 or the AL8805.
Note that when driving loads of two or more LEDs, the forward drop will normally be sufficient to prevent the device from switching below approximately 6 V . This will minimize the risk of damage to the device.

## Application Information (cont.)

## Thermal Considerations

When operating the device at high ambient temperatures, or when driving maximum load current, care must be taken to avoid exceeding the package power dissipation limits. The graph below gives details for power derating. This assumes the device to be mounted on a $25 \mathrm{~mm}{ }^{2}$ PCB with 1oz copper standing in still air.


Note that the device power dissipation will most often be a maximum at minimum supply voltage. It will also increase if the efficiency of the circuit is low. This may result from the use of unsuitable coils, or excessive parasitic output capacitance on the switch output.

## Thermal Compensation of Output Current

High luminance LEDs often need to be supplied with a temperature compensated current in order to maintain stable and reliable operation at all drive levels. The LEDs are usually mounted remotely from the device so, for this reason, the temperature coefficients of the internal circuits for the ZXLD1362 have been optimized to minimize the change in output current when no compensation is employed. If output current compensation is required, it is possible to use an external temperature sensing network - normally using Negative Temperature Coefficient (NTC) thermistors and/or diodes, mounted very close to the LED(s). The output of the sensing network can be used to drive the ADJ pin in order to reduce output current with increasing temperature.

## Layout Considerations

## LX Pin

The LX pin of the device is a fast switching node, so PCB tracks should be kept as short as possible. To minimize ground 'bounce', the ground pin of the device should be soldered directly to the ground plane.

## Coil and Decoupling Capacitors and Current Sense Resistor

It is particularly important to mount the coil and the input decoupling capacitor as close to the device pins as possible to minimize parasitic resistance and inductance, which will degrade efficiency. It is also important to minimize any track resistance in series with current sense resistor Rs. Its best to connect $V_{I N}$ directly to one end of $R_{S}$ and ISENSE directly to the opposite end of $R_{s}$ with no other currents flowing in these tracks. It is important that the cathode current of the Schottky diode does not flow in a track between $\mathrm{R}_{\mathrm{S}}$ and $\mathrm{V}_{\mathrm{IN}}$ as this may give an apparent higher measure of current than is actual because of track resistance.

## Application Information (cont.)

## ADJ Pin

The ADJ pin is a high impedance input for voltages up to 1.35 V so, when left floating, PCB tracks to this pin should be as short as possible to reduce noise pickup. A 100 nF capacitor from the ADJ pin to ground will reduce frequency modulation of the output under these conditions. An additional series $3.3 \mathrm{k} \Omega$ resistor can also be used when driving the ADJ pin from an external circuit (see below). This resistor will provide filtering for low frequency noise and provide protection against high voltage transients.


## High Voltage Tracks

Avoid running any high voltage tracks close to the ADJ pin, to reduce the risk of leakage currents due to board contamination. The ADJ pin is soft-clamped for voltages above 1.35 V to desensitize it to leakage that might raise the ADJ pin voltage and cause excessive output current. However, a ground ring placed around the ADJ pin is recommended to minimize changes in output current under these conditions.

## Evaluation PCB

ZXLD1362 evaluation boards are available on request and provide quick testing of the ZXLD1362 device.

## Dimming Output Current Using PWM

## Low Frequency PWM Mode

When the ADJ pin is driven with a low frequency PWM signal (eg 100 Hz ), with a high level voltage $V_{\text {ADJ }}$ and a low level of zero, the output of the internal low pass filter will swing between 0 V and $\mathrm{V}_{\text {ADJ }}$, causing the input to the shutdown circuit to fall below its turn-off threshold (200mV nom) when the ADJ pin is low. This will cause the output current to be switched on and off at the PWM frequency, resulting in an average output current loutavg proportional to the PWM duty cycle.
(See Figure 4 - Low frequency PWM operating waveforms).


Figure 4 Low Frequency PWM Operating Waveforms
The average value of output current in this mode is given by:

$$
\text { loutavg }=0.1 \mathrm{D}_{\text {PWM }} / R_{\mathrm{S}}\left[\text { for } \mathrm{D}_{\text {PWM }}>0.001\right]
$$

This mode is preferable if optimum LED 'whiteness' is required. It will also provide the widest possible dimming range (approx. 1000:1) and higher efficiency at the expense of greater output ripple.

## Ordering Information



| Device <br> (Note 12) | Part Mark | Package <br> Code | Packaging | Reel size <br> $\mathbf{( m m )}$ | Reel width <br> $\mathbf{( m m})$ | Quantity <br> per reel | Part Number <br> Suffix | Qualification <br> (Note 11) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ZXLD1362ET5TA | 1362 | ET5 | TSOT25 | 180 | 8 | 3000 | TA | AEC-Q100 grade 1 |
| ZXLD1362QET5TA | 1362 | ET5 | TSOT25 | 180 | 8 | 3000 | TA | Automotive Grade |

Note: 11. ZXLD1362QET5 is classified as "Automotive Grade" and supports PPAP documentation. See ZXLD1362Q datasheet for more information.

## Marking Information



## Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.


| TSOT25 |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| Dim | Min | Max | Typ |  |
| A | - | 1.00 | - |  |
| A1 | 0.01 | 0.10 | - |  |
| A2 | 0.84 | 0.90 | - |  |
| D | - | - | 2.90 |  |
| E | - | - | 2.80 |  |
| E1 | - | - | 1.60 |  |
| b | 0.30 | 0.45 | - |  |
| c | 0.12 | 0.20 | - |  |
| e | - | - | 0.95 |  |
| e1 | - | - | 1.90 |  |
| L | 0.30 | 0.50 |  |  |
| L2 | - | - | 0.25 |  |
| $\boldsymbol{\theta}$ | $0^{\circ}$ | $8^{\circ}$ | $4^{\circ}$ |  |
| $\boldsymbol{\theta 1}$ | $4^{\circ}$ | $12^{\circ}$ | - |  |
| All Dimensions in $\mathbf{~ m m}$ |  |  |  |  |
|  |  |  |  |  |

## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.


| Dimensions | Value (in $\mathbf{~ m m}$ ) |
| :---: | :---: |
| $\mathbf{C}$ | 0.950 |
| $\mathbf{X}$ | 0.700 |
| $\mathbf{Y}$ | 1.000 |
| $\mathbf{Y 1}$ | 3.199 |

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